

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

Claims 1-18 (Canceled)

Claim 19 (New): A method for manufacturing a light emitting device, comprising:  
forming a thin film transistor over a substrate;  
forming a first insulating film over the thin film transistor;  
performing a first plasma treatment on the first insulating film;  
forming a first electrode over the first insulating film, wherein the first electrode is electrically connected to the thin film transistor;  
forming a second insulating film over the first insulating film and an edge portion of the first electrode;  
performing a second plasma treatment at least on the second insulating film; forming a polymer film on the first electrode and the second insulating film; forming a low molecular weight film on the polymer film; and  
forming a second on the low molecular weight film.

Claim 20 (New): A method according to claim 19, wherein the polymer film is a luminescent layer and the low molecular weight film is an electron transport layer or an electron injection layer.

Claim 21 (New): A method according to claim 19, wherein the light emitting device is incorporated into an electronic device selected from the group consisting of a video camera, a

digital camera, a goggle type display, a navigation system, a personal computer, and a portable information terminal.

Claim 22 (New): A method for manufacturing a light emitting device, comprising:  
forming a thin film transistor over a substrate;  
forming a first insulating film over the thin film transistor;  
performing a first plasma treatment on the first insulating film;  
forming a first electrode over the first insulating film, wherein the first electrode is electrically connected to the thin film transistor;  
forming a second insulating film over the first insulating film and an edge portion of the first electrode;  
performing a second plasma treatment at least on the second insulating film; forming a polymer film on the first electrode and the second insulating film; forming a low molecular weight film on the polymer film; and  
forming a second on the low molecular weight film,  
wherein upper surfaces of the first and second insulating films are hardened.

Claim 23 (New): A method according to claim 22, wherein the polymer film is a luminescent layer and the low molecular weight film is an electron transport layer or an electron injection layer.

Claim 24 (New): A method according to claim 22, wherein the light emitting device is incorporated into an electronic device selected from the group consisting of a video camera, a digital camera, a goggle type display, a navigation system, a personal computer, and a portable information terminal.

Claim 25 (New): A method for manufacturing a light emitting device, comprising:  
forming a thin film transistor over a substrate;

forming a first insulating film over the thin film transistor;  
performing a plasma treatment on the first insulating film;  
forming a first electrode over the first insulating film, wherein the first electrode is electrically connected to the thin film transistor;  
forming a second insulating film over the first insulating film and an edge portion of the first electrode;  
forming a third insulating film on the second insulating film;  
forming a polymer film on the first electrode and the second insulating film;  
forming a low molecular weight film on the polymer film; and  
forming a second on the low molecular weight film,  
wherein the third insulating film is a diamond-like carbon film or a silicon nitride film.

Claim 26 (New): A method according to claim 25, wherein the polymer film is a luminescent layer and said low molecular weight film is an electron transport layer or an electron injection layer.

Claim 27 (New): A method according to claim 25, wherein the light emitting device is incorporated into an electronic device selected from the group consisting of a video camera, a digital camera, a goggle type display, a navigation system, a personal computer, and a portable information terminal.

Claim 28 (New): A method for manufacturing a light emitting device, comprising:  
forming a thin film transistor over a substrate;  
forming a first insulating film over the thin film transistor;  
performing a plasma treatment on the first insulating film;  
forming a first electrode over the first insulating film, wherein the first electrode is electrically connected to the thin film transistor;

forming a second insulating film over the first insulating film and an edge portion of the first electrode;  
forming a third insulating film on the second insulating film;  
forming a polymer film on the first electrode and the second insulating film;  
forming a low molecular weight film on the polymer film; and  
forming a second on the low molecular weight film,  
wherein the third insulating film is a diamond-like carbon film or a silicon nitride film,  
and  
wherein an upper surface of the first insulating film is hardened.

Claim 29 (New): A method according to claim 28, wherein the polymer film is a luminescent layer and said low molecular weight film is an electron transport layer or an electron injection layer.

Claim 30 (New): A method according to claim 28, wherein the light emitting device is incorporated into an electronic device selected from the group consisting of a video camera, a digital camera, a goggle type display, a navigation system, a personal computer, and a portable information terminal.

Claim 31 (New): A method for manufacturing a light emitting device, comprising:  
forming a thin film transistor over a substrate;  
forming a first insulating film over the thin film transistor;  
forming a second insulating film on the first insulating film;  
forming a first electrode over the second insulating film, wherein the first electrode is electrically connected to the thin film transistor;  
forming a third insulating film over the second insulating film and an edge portion of the first electrode;  
forming a fourth insulating film on the third insulating film;

forming a polymer film on the first electrode and the second insulating film;  
forming a low molecular weight film on the polymer film; and  
forming a second on the low molecular weight film,  
wherein the second and fourth insulating film is a diamond-like carbon film or a silicon nitride film.

Claim 32 (New): A method according to claim 31, wherein the polymer film is a luminescent layer and said low molecular weight film is an electron transport layer or an electron injection layer.

Claim 33 (New): A method according to claim 31, wherein the light emitting device is incorporated into an electronic device selected from the group consisting of a video camera, a digital camera, a goggle type display, a navigation system, a personal computer, and a portable information terminal.